

Standard Rectifier Module

V_{RRM} = 2x 1400 V

I_{FAV} = 270 A

V_F = 1,08 V

Phase leg

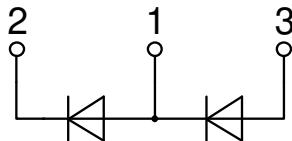
Part number

MDD255-14N1



Backside: isolated

 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: Y1

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Disclaimer Notice

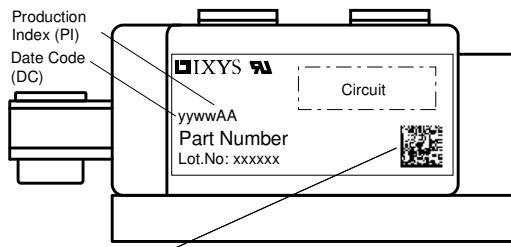
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Rectifier

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ C$			1500	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ C$			1400	V
I_R	reverse current	$V_R = 1400 V$ $V_R = 1400 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 150^\circ C$		500 20	μA mA
V_F	forward voltage drop	$I_F = 300 A$ $I_F = 600 A$ $I_F = 300 A$ $I_F = 600 A$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		1,19 1,40 1,08 1,35	V V
I_{FAV}	average forward current	$T_C = 100^\circ C$	$T_{VJ} = 150^\circ C$		270	A
$I_{F(RMS)}$	RMS forward current	180° sine			450	A
V_{FO} r_F	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 150^\circ C$		0,80 0,6	V $m\Omega$
R_{thJC}	thermal resistance junction to case				0,14	K/W
R_{thCH}	thermal resistance case to heatsink			0,04		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ C$		890	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 V$ $T_{VJ} = 150^\circ C$ $V_R = 0 V$		9,80 10,6 8,33 9,00	kA kA kA kA
I^2t	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 V$ $T_{VJ} = 150^\circ C$ $V_R = 0 V$		480,2 466,1 346,9 336,6	kA^2s kA^2s kA^2s kA^2s
C_J	junction capacitance	$V_R = 400 V; f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$		381	pF

Package Y1

Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			600	A
T_{VJ}	virtual junction temperature		-40		150	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		125	°C
Weight				680		g
M_D	mounting torque		4,5		7	Nm
M_T	terminal torque		11		13	Nm
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	16,0			mm
$d_{Spb/Apb}$		terminal to backside	16,0			mm
V_{ISOL}	isolation voltage	$t = 1$ second $t = 1$ minute	4800 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	4000		V V



Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDD255-14N1	MDD255-14N1	Box	3	464007

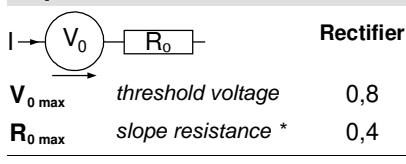
Similar Part	Package	Voltage class
MDD255-12N1	Y1-CU	1200
MDD255-16N1	Y1-CU	1600
MDD255-18N1	Y1-CU	1800
MDD255-20N1	Y1-CU	2000

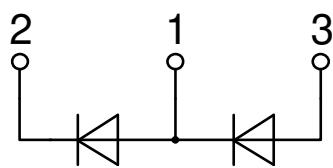
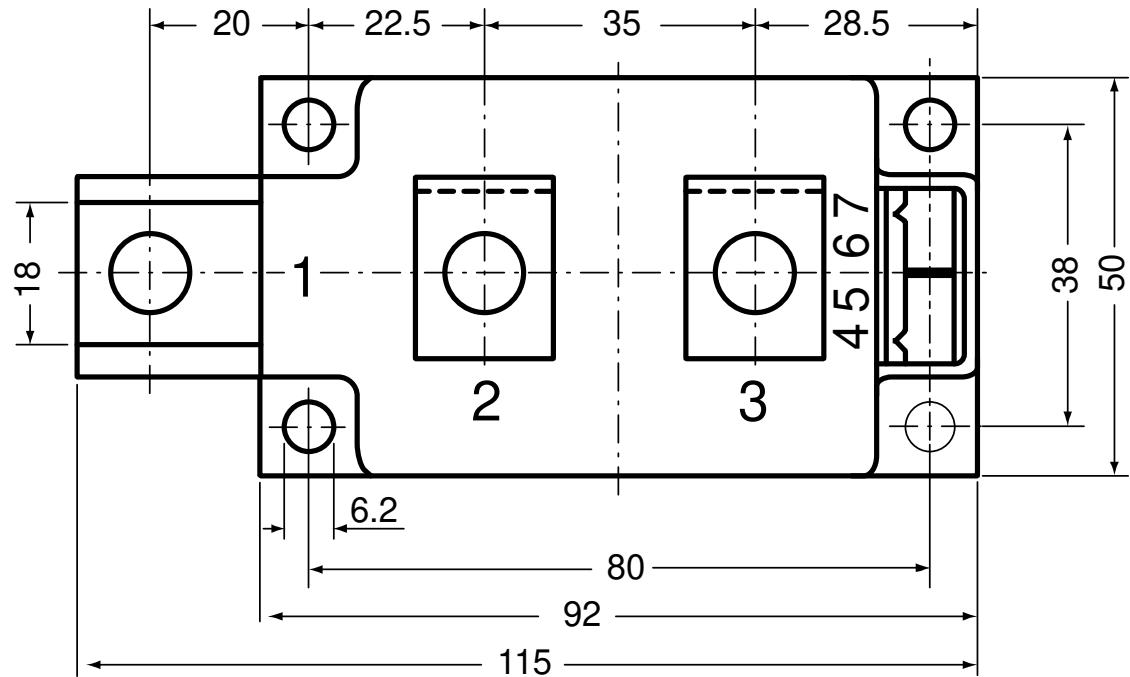
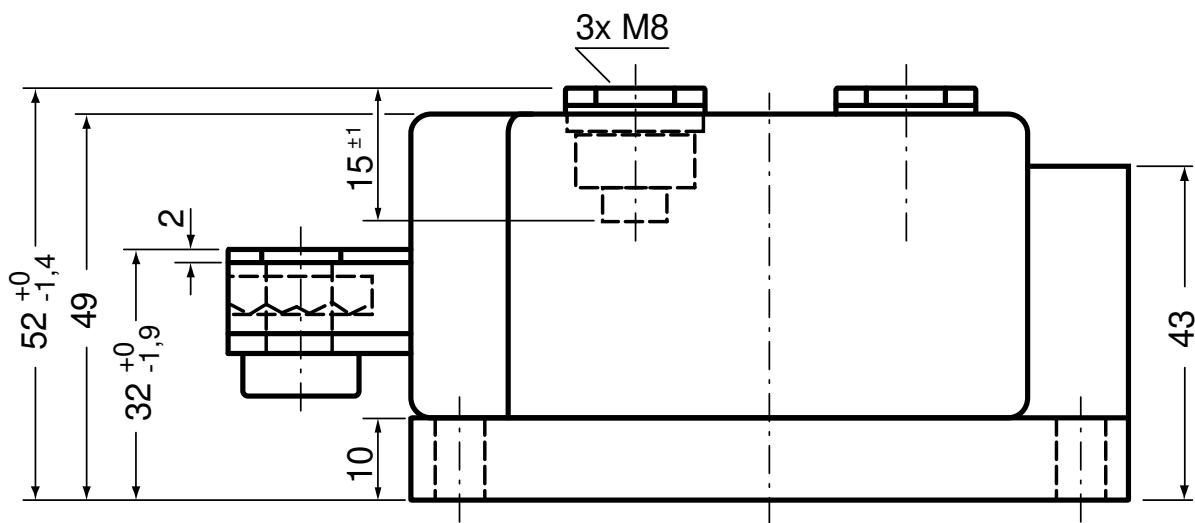
MDD255-22N1	Y1-CU	2200
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Equivalent Circuits for Simulation

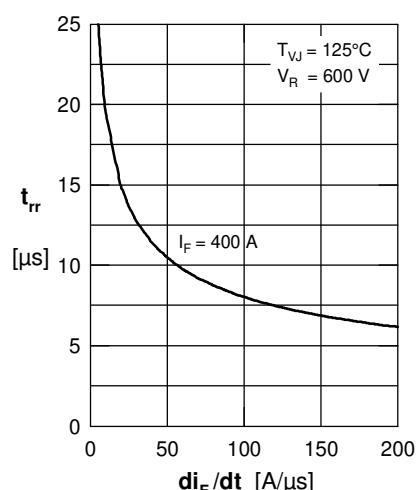
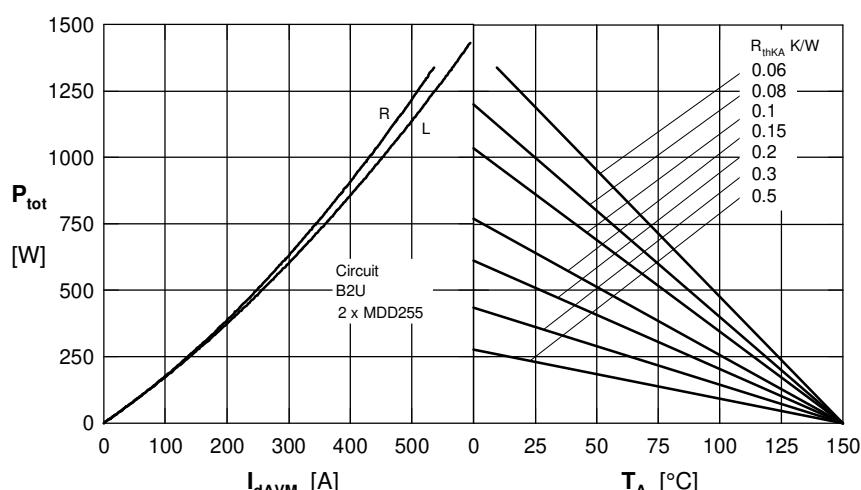
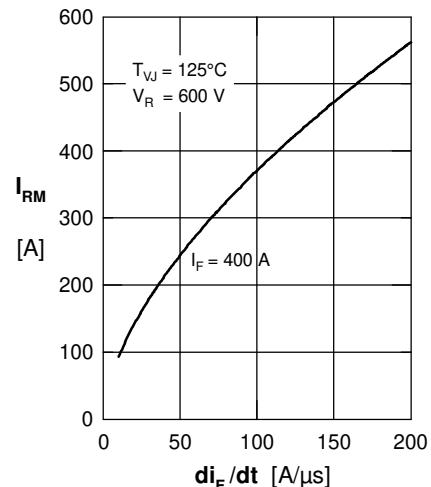
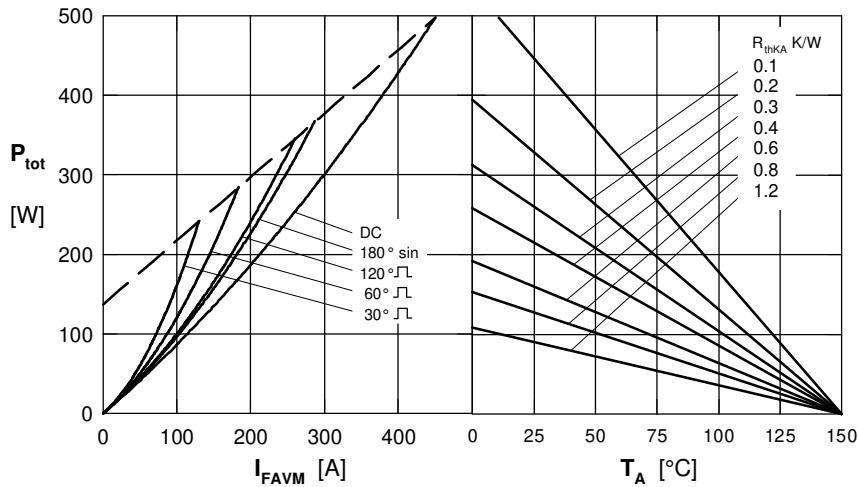
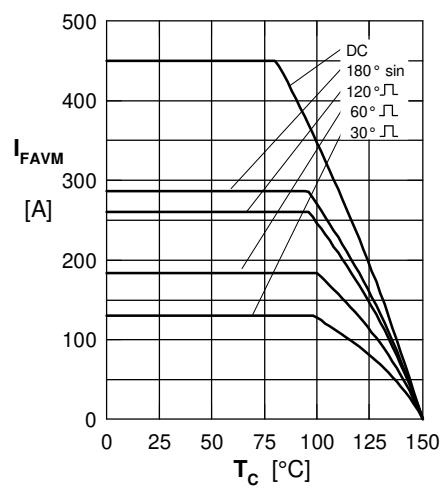
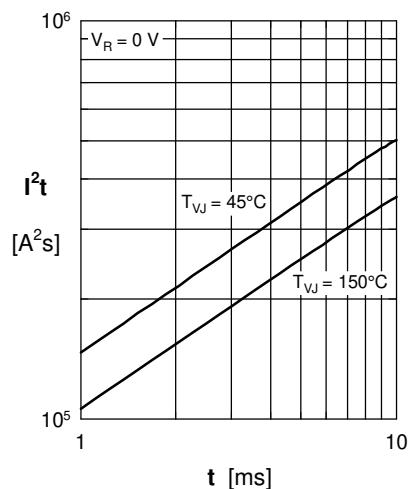
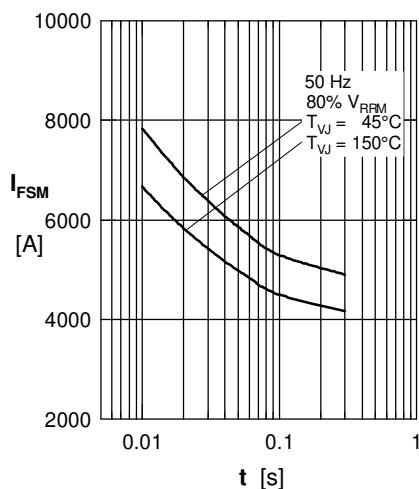
* on die level

$T_{VJ} = 150^\circ\text{C}$



Outlines Y1


Rectifier



Rectifier

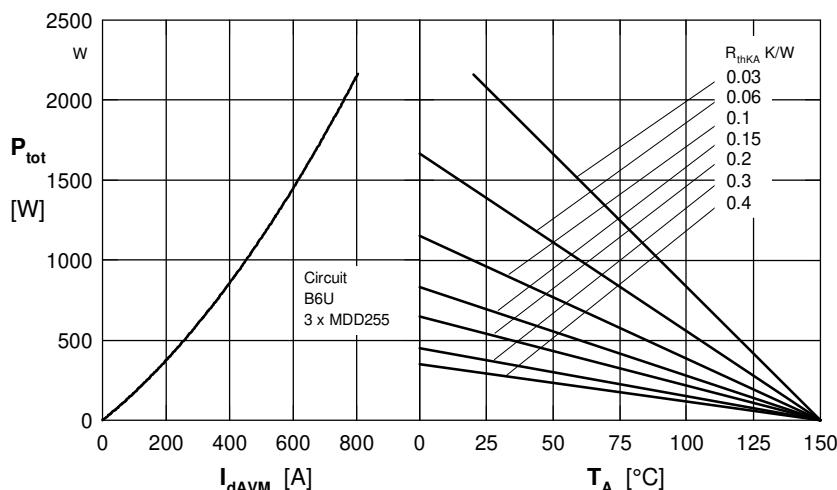


Fig. 8 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

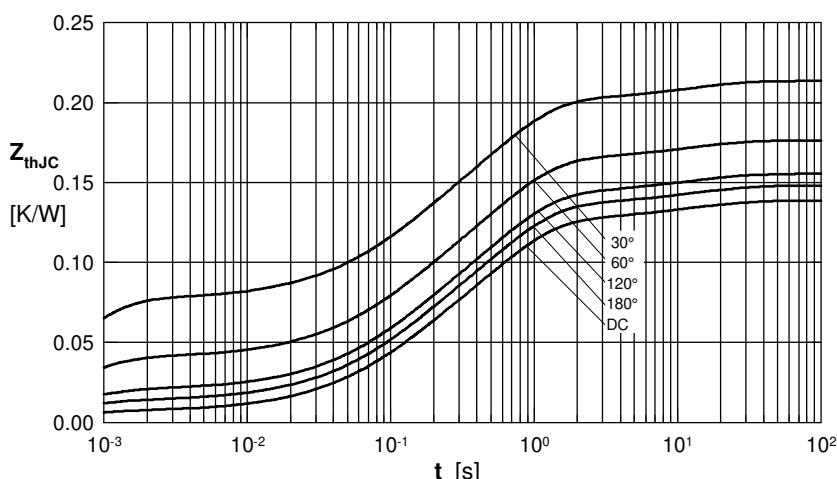


Fig. 9 Transient thermal impedance junction to case (per diode)

R_{thJC} for various conduction angles d:

d	R_{thJC} [K/W]
DC	0.139
180°	0.148
120°	0.156
60°	0.176
30°	0.214

Constants for Z_{thJC} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.0066	0.00054
2	0.0358	0.09800
3	0.0831	0.54000
4	0.0129	12.0000

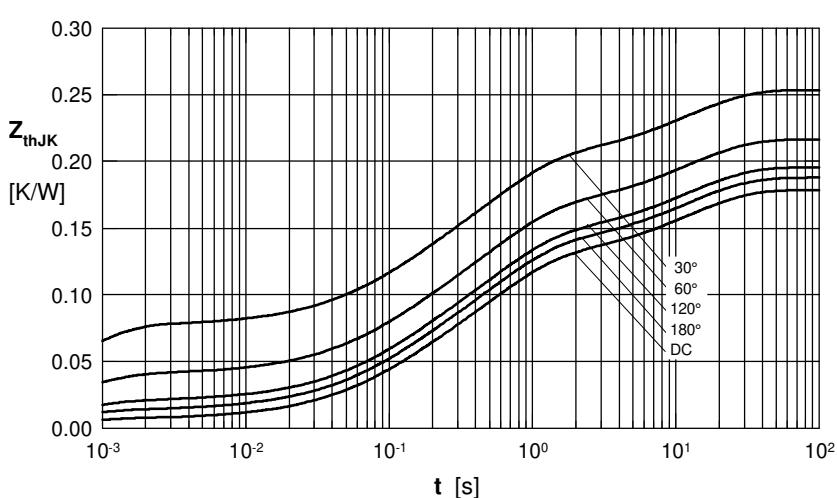


Fig. 10 Transient thermal impedance junction to heatsink (per diode)

R_{thJK} for various conduction angles d:

d	R_{thJK} [K/W]
DC	0.179
180°	0.188
120°	0.196
60°	0.216
30°	0.254

Constants for Z_{thJK} calculation:

i	R_{thi} [K/W]	t_i (s)
1	0.0066	0.00054
2	0.0358	0.09800
3	0.0831	0.54000
4	0.0129	12.0000
5	0.0400	12.0000